# NSN 5961-00-051-7910

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AeroBase Group

View Online at https://aerobasegroup.com/nsn/5961-00-051-7910

#### Inclosure Material:

Metal

**Overall Length:** 

0.475 inches

# Mounting Facility Quantity:

1

## Internal Configuration:

Junction contact

#### Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Threaded stud

#### **Features Provided:**

Hermetically sealed case

#### **Overall Width Across Flats:**

0.250 inches

#### Thread Size:

0.164 inches

#### Semiconductor Material:

Germanium

# Voltage Rating In Volts Per Characteristic:

25.0 breakdown voltage, collector-to-base, emitter open and 25.0 breakdown voltage, collector-to-emitter, base open and 25.0

breakdown voltage, emitter-to-base, collector open

# **Current Rating Per Characteristic:**

2.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

1.0 watts small-signal input power, common-collector

#### Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: pnp

#### **Thread Series Designator:**

Unf

# Terminal Type And Quantity:

3 uninsulated wire lead

# **Specification Data:**

80131-release2417 professional/industrial association specification

# Shelf Life:

N/a

# Unit Of Measure:

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## Demilitarization:

No

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